VHF linear power transistor

BLV33

Description:

NPN silicon planar epitaxial transistor encapsulated in a 1/16" 4 fslead SOT147 capstan package with ceramic cap. All leads are isolated from the stud. Primarily intended for use in linear VHF amplifiers for television transmitters and transposers.

Features

- * Diffused emitter ballasting resistors for an optimum temperature profile
- * Gold sandwich metallization ensures excellent reliability.

Specifications:

MODE OF OPERATION	f _{vision} (MHz)	V _{CE} (V)	I _C , I _{C(ZS)} (A)	T _h (°C)	d _{im} ⁽¹⁾ (dB)	P _{o sync} ⁽¹⁾ (W)	G _P (dB)	sync compr. ⁽²⁾ sync in/sync out (%)
CW, class-A	224.25	25	3.2	70	-55	>16.5	>9	
				25	-55	typ. 26	typ. 9.7	
CW, class-AB	224.25	28	0.1	70		typ. 90	typ. 6.5	30/25

Drawings:

PINNING - SOT147

PIN	SYMBOL	DESCRIPTION			
1	С	collector			
2	е	emitter			
3	b	base			
4	е	emitter			

